

1SP0335x2xx-MBN500H65E2 Preliminary Data Sheet

Compact, high-performance, plug-and-play single-channel IGBT driver based on SCALE™-2 technology for individual and parallel-connected modules in 2-level, 3-level and multilevel converter topologies

Abstract

The SCALE™-2 plug-and-play driver 1SP0335x2xx-MBN500H65E2 is a compact single-channel intelligent gate driver designed for Hitachi IGBTs MBN500H65E2. The master driver 1SP0335x2Mx-MBN500H65E2 features a fiber-optic interface. It can be used as stand-alone driver or in conjunction with up to three 1SP0335D2Sx-MBN500H65E2 slaves to drive up to four parallel-connected IGBT modules of type MBN500H65E2.

The DC/DC power supply must be purchased as a separate unit (one per master driver).

For drivers adapted to other types of high-power and high-voltage IGBT modules, refer to:

www.IGBT-Driver.com/go/plug-and-play

Features

- ✓ Plug-and-play solution
- ✓ Allows parallel connection of IGBT modules
- ✓ For 2-level, 3-level and multilevel topologies.
- ✓ Fiber-optic links (master)
- ✓ Built-in interface to 1SP0335D2Sx (slave)
- ✓ Duty cycle 0...100%
- ✓ Dynamic Advanced Active Clamping DA²C
- ✓ Dynamic IGBT short-circuit protection
- ✓ Monitoring of supply voltage
- ✓ Monitoring of gate voltage
- ✓ Extremely reliable; long service life
- ✓ Shortens application development time
- ✓ Suitable for MBN500H65E2

Applications

- ✓ Traction
- ✓ Railroad power supplies
- ✓ Light rail vehicles
- ✓ HVDC
- ✓ Flexible AC transmission systems (FACTS)
- ✓ Medium-voltage converters
- ✓ Industrial drives
- ✓ Wind-power converters
- Medical applications
- ✓ Research
- ✓ And many others



Safety Notice!

The data contained in this data sheet is intended exclusively for technically trained staff. Handling all high-voltage equipment involves risk to life. Strict compliance with the respective safety regulations is mandatory!

Any handling of electronic devices is subject to the general specifications for protecting electrostatic-sensitive devices according to international standard IEC 60747-1, Chapter IX or European standard EN 100015 (i.e. the workplace, tools, etc. must comply with these standards). Otherwise, this product may be damaged.

Important Product Documentation

This data sheet contains only product-specific data. For a detailed description, must-read application notes and common data that apply to the whole series, please refer to the "Description & Application Manual for 1SP0335 SCALE-2 IGBT Drivers" on www.IGBT-Driver.com/go/1SP0335.

When applying SCALE-2 plug-and-play drivers, please note that these drivers are specifically adapted to a particular type of IGBT module. Therefore, the type designation of SCALE-2 plug-and-play drivers also includes the type designation of the corresponding IGBT module. These drivers are not valid for IGBT modules other than those specified. Incorrect use may result in failure.

Mechanical Dimensions

Dimensions: See the relevant "Description and Application Manual"

Mounting principle: Connected to IGBT module with screws

Fiber-Optic Interfaces (1SP0335x2Mx)

Interface	Remarks	Part type #
Drive signal input Drive signal input Status output	1SP0335V, fiber-optic receiver (Notes 1, 2) 1SP0335S, fiber-optic receiver (Notes 1, 2) 1SP0335V, fiber-optic transmitter (Notes 1, 3)	HFBR-2522ETZ HFBR-2412Z HFBR-1522ETZ
Status output	1SP0335S, fiber-optic transmitter (Notes 1, 3)	HFBR-1412Z

Electrical Connectors

Interface	Remarks	Part type #
Power supply connector X1 Bus connectors X2 and X3	On-board connector (Note 4) On-board connectors (Note 5)	214012 214013



Absolute Maximum Ratings

Parameter	Remarks	Min	Max	Unit
Supply voltage V _{DC}	VDC to COM	0	30	V
Average supply current I _{DC}	1SP0335x2Mx only (Note 6)		215	mA
Average supply current I _{DC}	1SP0335x2Mx with three 1SP0335D2Sx (Note 6)		740	mA
Gate output power	1SP0335x2Mx, Ta < 70°C (Note 7)		3.5	W
	$1SP0335x2Mx$, $Ta = 85^{\circ}C$ (Note 7)		2.5	W
Gate output power	1SP0335D2Sx, Ta < 70°C (Note 8)		3.3	W
	1SP0335D2Sx, Ta = 85°C (Note 8)		2.3	W
Switching frequency F	1SP0335x2Mx, Ta < 70°C		15	kHz
	$1SP0335x2Mx$, $Ta = 85^{\circ}C$		10.5	kHz
Switching frequency F	1SP0335D2Sx, Ta < 70°C		14	kHz
	$1SP0335D2Sx$, $Ta = 85^{\circ}C$		9.5	kHz
Gate peak current I _{out}	Note 9	-35	+35	Α
DC-link voltage	Switching operation (Note 10)		4400	V
	Off state (Note 11)		5200	V
Operating voltage	Collector-emitter voltage		6500	V_{peak}
Max. emitter-emitter voltage	Between parallel connected drivers (Note 12)		200	V_{peak}
dV/dt	Between parallel connected drivers (Note 13)		50	kV/μs
Max. interface current	X2 and X3, total RMS value (Note 14)		4	A_{rms}
	X2 and X3, total peak value (Note 14)		20	A_{peak}
Operating temperature		-40	+85	°C
Storage temperature		-40	+90	°C

Recommended Operating Conditions

Power Supply	Remarks	Min	Тур	Max	Unit
Supply voltage V _{DC}	To COM	23.5	25	26.5	V



Electrical Characteristics

All data refer to +25°C and V_{DC} = 25V unless otherwise specified

Remarks	Min	Тур	Max	Unit
Without load, only 1SP0335x2Mx Without load, per additional 1SP0335D2Sx		45 20		mA mA
Remarks	Min	Тур	Max	Unit
Clear fault	12.1	12.6	13.1	V
Set fault (Note 15)	11.5	12.0	12.5	V
Set/clear fault	0.35			V
Clear fault	5	5.15	5.3	V
Set fault (Note 15)	4.7	4.85	5	V
Set/clear fault	0.15			V
Remarks	Min	Тур	Max	Unit
		VDC		V
To COM		0		V
To COM		15		V
Remarks	Min	Тур	Max	Unit
G _{mean} to E, set fault (Note 16)		12.9		V
G _{mean} to E, set fault (Note 16)		-7.6		V
Turn-on (Note 16)		28		μs
Turn-off (Note 16)		42		μs
Remarks	Min	Тур	Max	Unit
Between auxiliary terminals (Note 17)		247		V
DC-link voltage = 4400V (Note 18)		5.9		μs
DC-link voltage = 3000V (Note 18)		6		μs
DC-link voltage = 2200V (Note 18)		6.4		μs
DC-link voltage = 1500V (Note 18)		10.2		μs
After the response time (Note 19)		0.3		μs
Remarks	Min	Тур	Max	Unit
Note 20		190		ns
Note 20		185		ns
Remarks	Min	Тур	Max	Unit
G to E (Note 21)		9		ns
G to E (Note 21)		20		ns
	Without load, only 1SP0335x2Mx Without load, per additional 1SP0335D2Sx Remarks Clear fault Set fault (Note 15) Set/clear fault Clear fault Set fault (Note 15) Set/clear fault Remarks To COM To COM To COM Remarks Gmean to E, set fault (Note 16) Turn-on (Note 16) Turn-off (Note 16) Remarks Between auxiliary terminals (Note 17) DC-link voltage = 4400V (Note 18) DC-link voltage = 3000V (Note 18) DC-link voltage = 2200V (Note 18) DC-link voltage = 1500V (Note 18) After the response time (Note 19) Remarks Note 20 Note 20 Remarks G to E (Note 21)	Without load, only 1SP0335x2Mx Without load, per additional 1SP0335D2Sx Remarks Min Clear fault 12.1 Set fault (Note 15) 11.5 Set/clear fault 5 Set fault (Note 15) 4.7 Set fault (Note 15) 4.7 Set/clear fault 0.15 Remarks Min To COM To COM To COM Remarks Min Gmean to E, set fault (Note 16) Gmean to E, set fault (Note 16) Turn-on (Note 16) Turn-of (Note 16) Turn-off (Note 16) Remarks Min Between auxiliary terminals (Note 17) DC-link voltage = 4400V (Note 18) DC-link voltage = 3000V (Note 18) DC-link voltage = 2200V (Note 18) DC-link voltage = 1500V (Note 18) After the response time (Note 19) Remarks Min Note 20 Note 20 Remarks Min	Without load, only 1SP0335x2Mx Without load, per additional 1SP0335D2Sx 20	Without load, only 1SP0335x2Mx Without load, per additional 1SP0335D2Sx 20



Timing Characteristics	Remarks	Min	Тур	Max	Unit
Transmission delay of fault state	Note 22		90		ns
Delay to clear fault state	After IGBT short circuit (Note 23)		9		μs
	After gate-monitoring fault (Notes 23, 27)		1		μs
Acknowledge delay time	Note 24		250		ns
Acknowledge pulse width	On host side	400	700	1050	ns
Gate Output	Remarks	Min	Тур	Max	Unit
Turn-on gate resistor R _{g(on)}	Note 25		12.5		Ω
Turn-off gate resistor R _{g(off)}	Note 25	12.5		Ω	
Auxiliary gate capacitor C _{ge}		not assembled		nF	
Gate voltage at turn-on	Note 26	15		V	
Gate-voltage at turn-off	Note 26	-10		V	

Footnotes to the Key Data

- 1) The transceivers required on the host controller side are not supplied with the gate driver. It is recommended to use the same types as used in the gate driver. For product information refer to www.IGBT-Driver.com/go/fiberoptics
- 2) The recommended transmitter current at the host controller is 20mA. A higher current may increase jitter or delay at turn-off.
- 3) The typical transmitter current at the gate driver is 18mA. In case of supply undervoltage, the minimum transmitter current at the gate driver is 12mA: this is suitable for adequate plastic optical fibers with a length of more than 10 meters.
- 4) This refers to the manufacturer ordering number, see www.igbt-driver.com/go/ext_erni. The customer-side connector as well as cables with different lengths can be supplied by CONCEPT. Refer to the "Description & Application Manual for 1SP0335 SCALE-2 IGBT Drivers" for more information.
- 5) This refers to the manufacturer ordering number, see www.igbt-driver.com/go/ext_erni. These connectors are to be used to connect 1SP0335x2Mx (master) or 1SP0335D2Sx (slave) to 1SP0335D2Sx (slave) if parallel connection of IGBT modules is required. Cables with different lengths can be supplied by CONCEPT. Refer to the "Description & Application Manual for 1SP0335 SCALE-2 IGBT Drivers" for more information.
- 6) If the specified value is exceeded, this indicates a driver overload. It should be noted that the driver is not protected against overload.
- 7) The given power can only be fully exploited without slaves 1SP0335D2Sx (no parallel connection of IGBT modules). If the specified value is exceeded, this indicates a driver overload. It should be noted that the driver is not protected against overload. From 70°C to 85°C, the maximum permissible output power can be linearly interpolated from the given data.
- 8) The given power can be fully exploited with slaves 1SP0335D2Sx (parallel connection of IGBT modules). If the specified value is exceeded, this indicates a driver overload. It should be noted that the driver is not protected against overload. From 70°C to 85°C, the maximum permissible output power can be linearly interpolated from the given data.
- 9) The gate current is limited by the gate resistors located on the driver.
- 10) This limit is due to active clamping under switching conditions. Refer to the "Description & Application Manual for 1SP0335 SCALE-2 IGBT Drivers".
- 11) Due to the Dynamic Active Advanced Clamping Function (DA²C) implemented on the driver, the DC-link voltage can be increased in the off-state condition (e.g. after emergency shut-down). This value is only valid when the IGBTs are in the off state (not switching). The time during which the voltage can be applied should be limited to short periods (< 60 seconds). Refer to the "Description & Application Manual for 1SP0335 SCALE-2 IGBT Drivers".



- 12) The maximum dynamic voltage between auxiliary emitters of parallel-connected drivers due to asymmetrical operation at turn-on and turn-off must be limited to the given value.
- 13) Maximum allowed rate of change of auxiliary emitter voltage of parallel connected drivers. This specification guarantees that the drive information will be transferred reliably even with high rate of change of auxiliary emitter voltages (asymmetrical operation).
- Dynamic voltages between auxiliary emitters of parallel connected drivers at turn-on and turn-off lead to equalizing currents over the X2 or X3 bus. The peak and RMS values of the resulting current must be limited to the given value.
- 15) Undervoltage monitoring of the secondary-side supply voltage (Viso to Vee and Vee to COM which correspond with the approximate turn-on and turn-off gate-emitter voltages). If the corresponding voltage drops below this limit on 1SP0335x2Mx (masters), all paralleled IGBTs (master and slaves) are switched off and a fault is transmitted to the status output. If the corresponding voltage drops below this limit on 1SP0335D2Sx (slaves), the corresponding IGBT is switched off. If the IGBT was turned on, a fault will be generated by the gate-monitoring function on the master which will turn off all paralleled IGBT after the corresponding delay.
- 16) The mean value $V_{GE,mean}$ of all gate voltages (master and all slaves) is filtered and compared to the given values at turn-on and turn-off. If the specified values are exceeded ($V_{GE,mean} < V_{GE,on,min}$ at turn-on resp. $V_{GE,mean} > V_{GE,off,max}$ at turn-off) after the given filter delay, the driver turns off all parallel-connected IGBTs and a fault is transmitted to the status output.
- 17) A dynamic Vce protection is implemented on the driver. The maximum allowed Vce voltage at turn-on is dynamically adjusted in order to better fit to the IGBT characteristics at turn-on. At the end of the turn-on process the given static value applies.
- 18) The resulting pulse width of the direct output of the gate drive unit for short-circuit type I (excluding the delay of the gate resistors) is the sum of the response time plus the delay to IGBT turn-off.
- 19) The turn-off event of the IGBT is delayed by the specified time after the response time.
- 20) Including the delay of the external fiber-optic links (cable length: 1m). Measured from the transition of the turn-on or turn-off command at the optical transmitter on the host controller side to the direct output of the gate drive unit (excluding the delay of the gate resistors).
- 21) Output rise and fall times are measured between 10% and 90% of the nominal output swing. The values are given for the driver side of the gate resistors with $2\Omega/1uF$ load. The time constant of the output load in conjunction with the present gate resistors leads to an additional delay at their load side.
- 22) Delay of external fiber-optic links. Measured from the driver secondary side (ASIC output) to the optical receiver on the host controller.
- 23) Measured on the host side. The fault status on the secondary side is automatically reset after the specified time.
- 24) Including the delay of the external fiber-optic links. Measured from the transition of the turn-on or turn-off command at the optical transmitter on the host controller side to the transition of the acknowledge signal at the optical receiver on the host controller side.
- 25) The gate resistors can be leaded or surface mounted. CONCEPT reserves the right to determine which type will be used. Typically, higher quantities will be produced with SMD resistors and small quantities with leaded resistors.
- 26) The driver supply voltage VDC is split into two distinct voltages on the driver. The first one is the turn-on voltage which is regulated at about 15V. The difference between VDC and the turn-on voltage is the turn-off voltage which is not regulated and mainly dependent on the driver input voltage VDC.
- 27) The fault status is set as long as the gate monitoring fault is present. The given value applies if the driver goes from the "off state" to the "on state" and the gate-emitter voltage of one or more parallel connected drivers does not turn on. If the driver goes from the "on state" to the "off state" and the gate-emitter voltage of one or more parallel connected drivers does not turn off, the fault status is applied as long as the gate monitoring fault is present.



Legal Disclaimer

The statements, technical information and recommendations contained herein are believed to be accurate as of the date hereof. All parameters, numbers, values and other technical data included in the technical information were calculated and determined to our best knowledge in accordance with the relevant technical norms (if any). They may base on assumptions or operational conditions that do not necessarily apply in general. We exclude any representation or warranty, express or implied, in relation to the accuracy or completeness of the statements, technical information and recommendations contained herein. No responsibility is accepted for the accuracy or sufficiency of any of the statements, technical information, recommendations or opinions communicated and any liability for any direct, indirect or consequential loss or damage suffered by any person arising therefrom is expressly disclaimed.